## NSN 5961-01-069-6240

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-069-6240 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Overall Height:** 0.155 inches **Overall Width:** 0.730 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 7.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Test Data Document:** 94987-129213 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 flange and 2 ribbon Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

## **NSN 5961-01-069-6240** Transistor - Page 2 of 2



Fiig:

A110a0